

# **Dual NPN General Purpose Amplifier Transistor**

## EMX1DXV6T1G, EMX1DXV6T5G

This NPN transistor is designed for general purpose amplifier applications. This device is housed in the SOT-563 package which is designed for low power surface mount applications, where board space is at a premium.

#### **Features**

- Reduces Board Space
- High h<sub>FE</sub>, 210-460 (Typical)
- Low V<sub>CE(sat)</sub>, < 0.5 V
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>(BR)CBO</sub>	60	Vdc
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc
Emitter-Base Voltage	V <sub>(BR)EBO</sub>	7.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

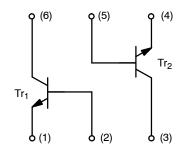
Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	357 (Note 1) 2.9 (Note 1)	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{ heta JA}$	350 (Note 1)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation $T_{\Delta} = 25^{\circ}C$	P <sub>D</sub>		
Derate above 25°C		500 (Note 1) 4.0 (Note 1)	mW mW/°C
, , , , , , , , , , , , , , , , , , ,	$R_{ heta JA}$	` ,	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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1. FR-4 @ Minimum Pad

### DUAL NPN GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT





SOT-563 CASE 463A STYLE 1

#### **MARKING DIAGRAM**



3X = Specific Device Code

M = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### EMX1DXV6T1G, EMX1DXV6T5G

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage ( $I_C = 50 \mu Adc, I_E = 0$ )	V <sub>(BR)CBO</sub>	60	-	-	Vdc
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)</sub> CEO	50	-	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 50 \mu Adc, I_E = 0$ )	V <sub>(BR)EBO</sub>	7.0	_	-	Vdc
Collector-Base Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	-	_	0.5	μΑ
Emitter-Base Cutoff Current (V <sub>EB</sub> = 7.0 Vdc, I <sub>B</sub> = 0)	I <sub>EBO</sub>	-	_	0.5	μΑ
Collector-Emitter Saturation Voltage (Note 2) $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	V <sub>CE(sat)</sub>	-	_	0.4	Vdc
DC Current Gain (Note 3) (V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 1.0 mAdc)	h <sub>FE</sub>	120	_	560	-
Transition Frequency ( $V_{CE} = 12 \text{ Vdc}, I_{C} = 2.0 \text{ mAdc}, f = 30 \text{ MHz}$ )	f <sub>T</sub>	-	180	-	MHz
Output Capacitance (V <sub>CB</sub> = 12 Vdc, I <sub>C</sub> = 0 Adc, f = 1 MHz)	C <sub>OB</sub>	-	2.0	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

#### **ORDERING INFORMATION**

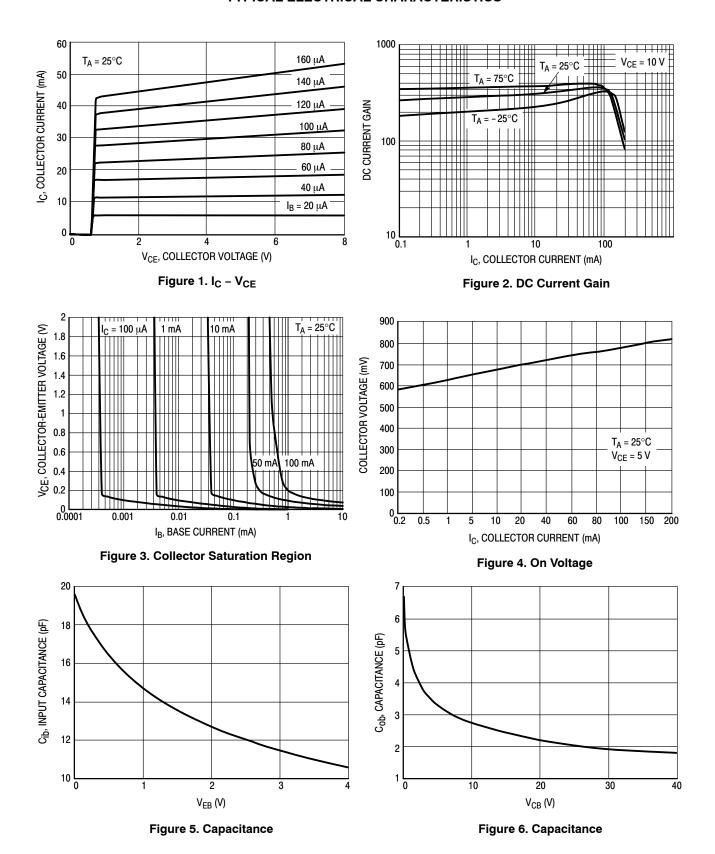
Device	Package	Shipping <sup>†</sup>
EMX1DXV6T1G, NSVEMX1DXV6T1G	SOT-563 (Pb-Free)	4000 Units / Tape & Reel
EMX1DXV6T5G	SOT-563 (Pb-Free)	8000 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>3.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, D.C.  $\leq$  2%.

#### EMX1DXV6T1G, EMX1DXV6T5G

#### TYPICAL ELECTRICAL CHARACTERISTICS



## MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



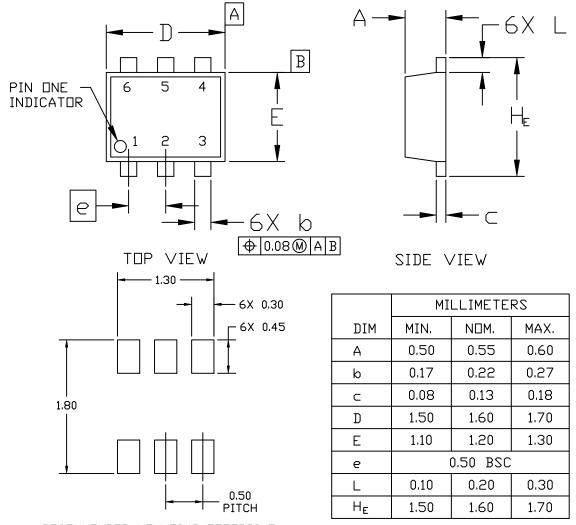


#### SOT-563, 6 LEAD CASE 463A ISSUE H

**DATE 26 JAN 2021** 

#### NOTES:

- I. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



#### RECOMMENDED MOUNTING FOOTPRINT\*

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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DESCRIPTION:	SOT-563, 6 LEAD		PAGE 1 OF 2	

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#### **SOT-563, 6 LEAD**

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**DATE 26 JAN 2021** 

STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1	STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1
STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE 4. ANODE 5. CATHODE 6. CATHODE	STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE	STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN	STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2 5. GATE 2 6. DRAIN 1
STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2 5. N/C 6. ANODE 1	STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	

## GENERIC MARKING DIAGRAM\*



XX = Specific Device CodeM = Month Code= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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